Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-465-4768

view Online at https://aerobasegroup.com/nsn/5961-01-465-4766
Inclosure Material:
Glass
Overall Length:
0.182 inches
Overall Width:
0.126 inches
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 peak gate voltage
Current Rating Per Characteristic:
5.50 amperes emitter current, dc peak
Power Rating Per Characteristic:
4.0 watts any acceptable preset
Test Data Document:
81349-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format;
excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental
and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
1 bonding pad
Specification Data:
81349-mil-s-19500/542f government specification
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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